# NSN 5962-01-157-9098

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# Body Length: 1.290 inches Body Width: Between 0.500 inches and 0.610 inches Body Height: 0.210 inches

**Maximum Power Dissipation Rating:** 

1.02 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and monolithic and schottky and bipolar and programmable and programmed and positive outputs

#### **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

13 input

## Case Outline Source And Designator:

D-3 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## Time Rating Per Chacteristic:

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

# Memory Capacity:

Unknown

#### **Special Features:**

Alter in acc0rdance w/g.E. Drawing 77a102340p1

## Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

24 printed circuit

#### Specification Data:

81340-mil-m-38510/208/usaf/ government specification

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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